Silylmanganese Pentacarbonyl; the Nature of Adducts of Silyl Compounds with Tertiary Amines

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Although two descriptions of the preparation of Ph₃SiMn(CO)₅ have appeared, 1,2 almost nothing is known about the chemistry of the Si-Mn bond. We now report on the parent compound, silylmanganese carbonyl, SiH₃Mn(CO)₅ [m.p., 25·5°; b.p. (extrapolated), 134°]. It is prepared analogously to silylcobalt carbonyl,3 and is generally less reespecially towards protic reagents. Carbonyl insertion into the Si-Mn bond has not been observed.

Tertiary amines such as trimethylamine and pyridine give rise to rather weak 1:2 (acceptor: base) adducts, while 2,2'-bipyridyl gives a weak 1:1 adduct. Typical infrared absorptions in the carbonyl stretching region are given in the Table.

Much stronger adducts of similar stoicheiometries are formed between SiH₃Co(CO)₄ and these amines; their v(CO) absorptions are also given. will be seen that all the adducts appear to contain the carbonylmetallate anion in the solid state, and can be formulated as $(SiH_3, 2B)^+$ $[M(CO)_n]^-$. There has been considerable speculation regarding the nature of adducts6 such as SiH₃I₂B; it has seemed probable (but not completely certain) that they could best be formulated as ionic species with five-co-ordinate silicon, viz., (SiH₃,2B)+I-, rather than as six-co-ordinate molecular adducts.7 This conclusion is now strengthened.

TABLE

Carbonvl stretching frequencies of SiH₃-Mn and SiH₃-Co devinatives

Compound	ν(CO) cm1
$SiH_3Mn(CO)_5$ (g)	2106,* 2021*
$SiH_3Mn(CO)_5$, $2C_5H_5N$ (s)	1860
SiH ₃ Mn(CO) ₅ , 2NMc ₃ (s)	1860
$Mn(CO)_5$ † (ref. 4)	1898, 1864
SiH ₃ Co(CO) ₄ (g)	2106,* 2051,* 2026*
$SiH_3Co(CO)_4,2C_5H_5N$ (s)	1882
SiH ₃ Co(CO) ₄ , 2NMe ₃ (s)	1870
$Co(CO)_4$ † (ref. 5)	1883, 1861 sh

* Centre of multiplet. † Sodium salt in tetrahydrofuran solution.

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